

Chemical and Physical Pressure Studies of Phosphorous Substituted BaFe_2As_2

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Replacing arsenic by phosphorous in BaFe_2As_2 induces superconductivity without introducing extra charge carriers; this isoelectronic substitution emulates the effect of physical pressure and is consequently known as chemical pressure. Applying physical pressure on substituted $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ therefore provides an interesting way to compare and contrast the interplay between chemical and physical pressure. We have performed AC susceptibility measurements on $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ under hydrostatic pressure and found a maximum T_c of 31 K for all combination of chemical and physical pressures. ¹ Additionally, we have studied the anisotropic superconducting properties of the optimally substituted $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ with $x = 0.35$, and found that the superconducting properties become more anisotropic under pressure despite a decreasing T_c . ²

¹L. E. Klintberg, S. K. Goh et al., J. Phys. Soc. Jpn. 79, 123706 (2010)

²S. K. Goh, Y. Nakai et al., Phys. Rev. B 80, 094502 (2010)